

**4-PIN DIP, 0.1  $\Omega$  LOW ON-STATE RESISTANCE**  
**2.0 A CONTINUOUS LOAD CURRENT**  
**1-ch Optical Coupled MOS FET**

–NEPOC Series–

**DESCRIPTION**

The PS710CL2-1A is a solid state relay containing a GaAs LED on the input side and MOS FETs on the output side.

It is suitable for PLC, etc. because of its large continuous load current and low on-state resistance.

The PS710CL2-1A has a surface mount type with 10.16 mm lead pitch.

**FEATURES**

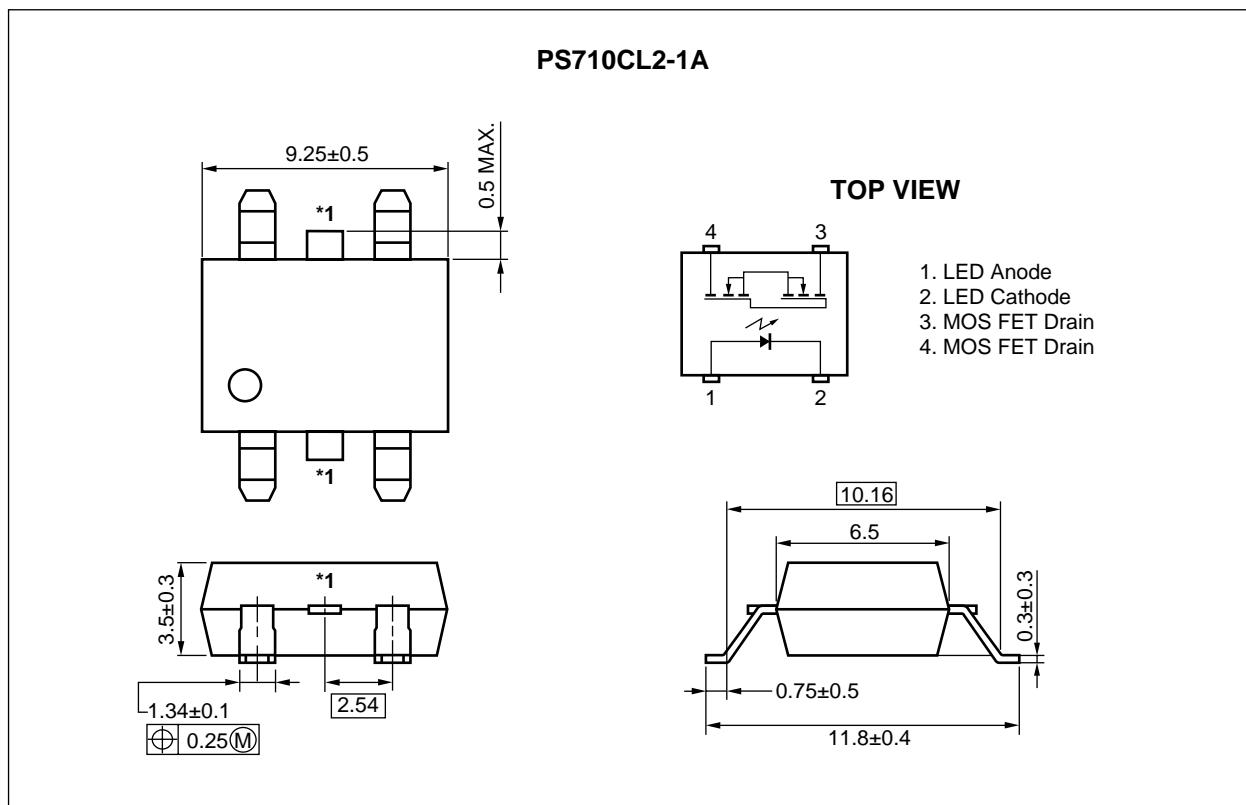
- Low on-state resistance ( $R_{on} = 0.1 \Omega$  TYP.)
- Large continuous load current ( $I_L = 2.0$  A)
- 1 channel type (1 a output)
- Low LED operating current ( $I_F = 2$  mA)
- Designed for AC/DC switching line changer
- Small package (4-pin DIP)
- Low offset voltage
- Ordering number of taping product: PS710CL2-1A-E3, E4

**APPLICATIONS**

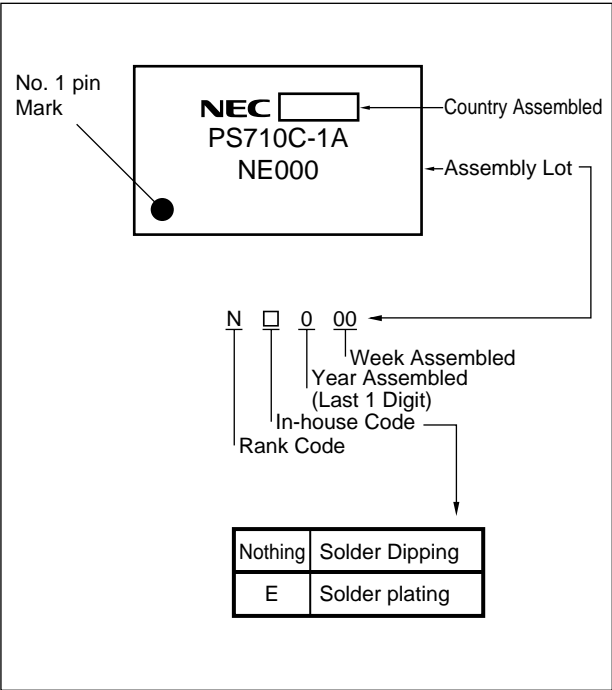
- Measurement equipment
- FA equipment

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PACKAGE DIMENSIONS (UNIT: mm)



MARKING EXAMPLE



**ORDERING INFORMATION**

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS710CL2-1A	4-pin DIP	Magazine case 50 pcs	PS710CL2-1A
PS710CL2-1A-E3		Embossed Tape 1 000 pcs/reel	
PS710CL2-1A-E4			

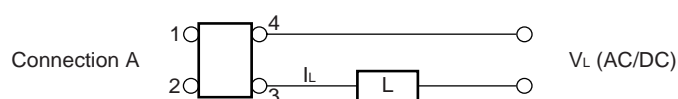
\*1 For the application of the Safety Standard, following part number should be used.

**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)**

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	$I_F$	50	mA
	Reverse Voltage	$V_R$	5.0	V
	Power Dissipation	$P_D$	50	mW
	Peak Forward Current <sup>*1</sup>	$I_{FP}$	1	A
MOS FET	Load Voltage	$V_L$	60	V
	Continuous Load Current <sup>*2</sup>	Connection A $I_L$	2.0	A
	Pulse Load Current <sup>*3</sup> (AC/DC Connection)	$I_{LP}$	4.0	A
	Power Dissipation	$P_D$	600	mW
Isolation Voltage <sup>*4</sup>		$BV$	1 500	Vr.m.s.
Total Power Dissipation		$P_T$	650	mW
Operating Ambient Temperature		$T_A$	-40 to +85	$^\circ\text{C}$
Storage Temperature		$T_{stg}$	-40 to +100	$^\circ\text{C}$

\*1  $PW = 100 \mu\text{s}$ , Duty Cycle = 1%

\*2 Conditions:  $I_F \geq 2 \text{ mA}$ . The following types of load connections are available.



\*3  $PW = 100 \text{ ms}$ , 1 shot

\*4 AC voltage for 1 minute at  $T_A = 25^\circ\text{C}$ ,  $RH = 60\%$  between input and output

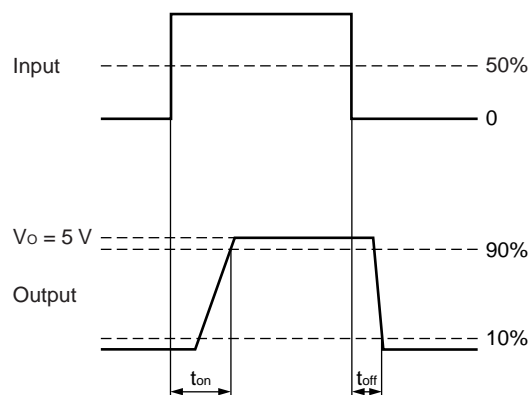
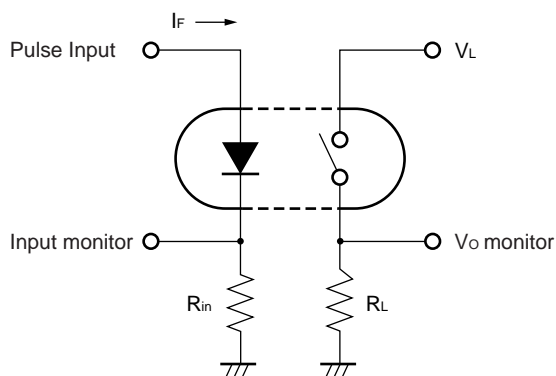
**RECOMMENDED OPERATING CONDITIONS ( $T_A = 25^\circ\text{C}$ )**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	$I_F$	2	10	20	mA
LED Off Voltage	$V_F$	0		0.5	V

**ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )**

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	$V_F$	$I_F = 10\text{ mA}$		1.2	1.4	V
	Reverse Current	$I_R$	$V_R = 5\text{ V}$			5.0	$\mu\text{A}$
MOS FET	Off-state Leakage Current	$I_{\text{Leak}}$	$V_D = 60\text{ V}$			1.0	$\mu\text{A}$
	Output Capacitance	$C_{\text{out}}$	$V_D = 0\text{ V}$ , $f = 1\text{ MHz}$		320		pF
Coupled	LED On-state Current	$I_{\text{Fon}}$	$I_L = 2.0\text{ A}$			2.0	mA
	On-state Resistance	$R_{\text{on}}$	$I_F = 10\text{ mA}$ , $I_L = 2.0\text{ A}$ , $t \leq 10\text{ ms}$		0.1	0.15	$\Omega$
	Turn-on Time <sup>*1,2</sup>	$t_{\text{on}}$	$I_F = 10\text{ mA}$ , $V_O = 5\text{ V}$ , $R_L = 500\text{ }\Omega$ ,		1.0	3.0	ms
	Turn-off Time <sup>*1,2</sup>	$t_{\text{off}}$	$PW \geq 10\text{ ms}$		0.05	1.0	
	Isolation Resistance	$R_{\text{I-O}}$	$V_{\text{I-O}} = 1.0\text{ kV}_{\text{DC}}$	$10^9$			$\Omega$
	Isolation Capacitance	$C_{\text{I-O}}$	$V = 0\text{ V}$ , $f = 1\text{ MHz}$		0.5		pF

**\*1 Test Circuit for Switching Time**

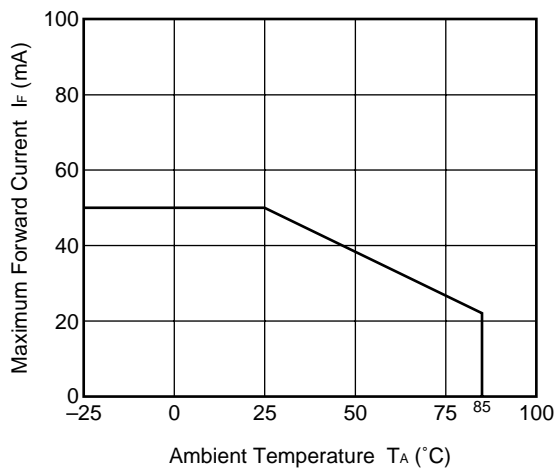


**\*2 The turn-on time and turn-off time are specified as input-pulse width  $\geq 10\text{ ms}$ .**

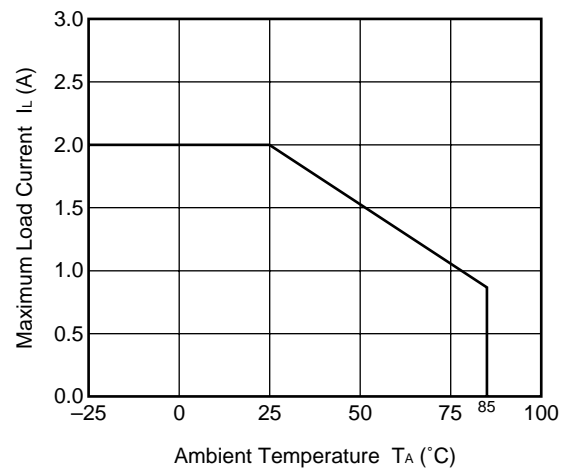
Be aware that when the device operates with an input-pulse width of under 10 ms, the turn-on time and turn-off time will increase.

**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , unless otherwise specified)**

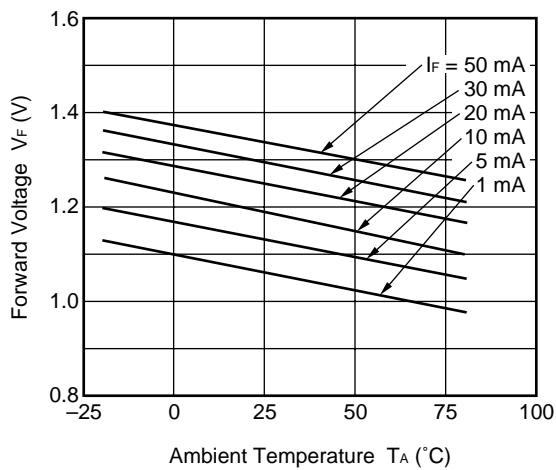
**MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE**



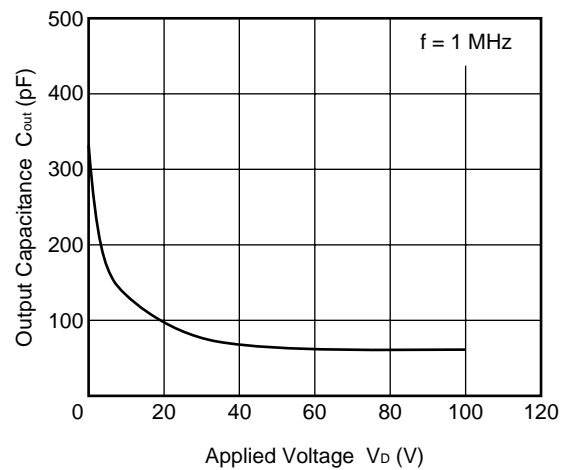
**MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE**



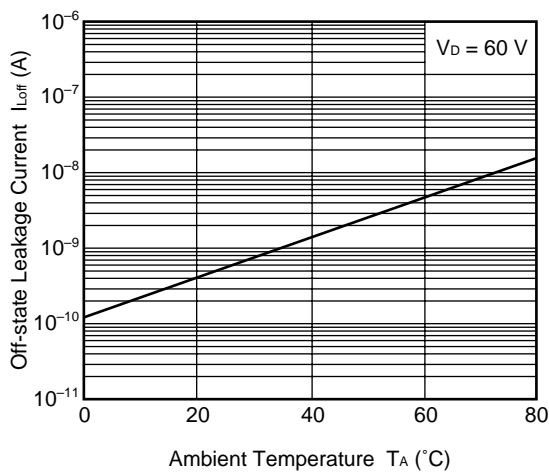
**FORWARD VOLTAGE vs. AMBIENT TEMPERATURE**



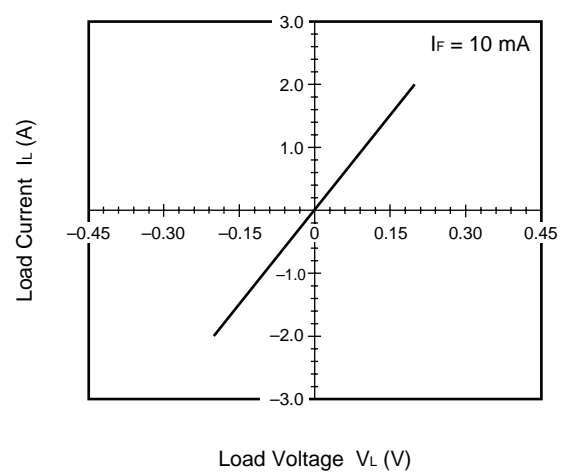
**OUTPUT CAPACITANCE vs. APPLIED VOLTAGE**



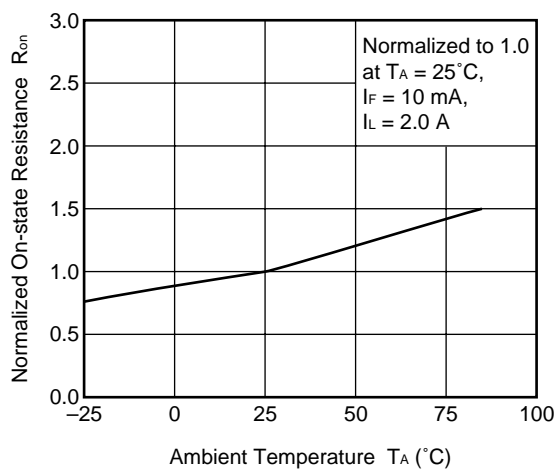
**OFF-STATE LEAKAGE CURRENT vs. AMBIENT TEMPERATURE**



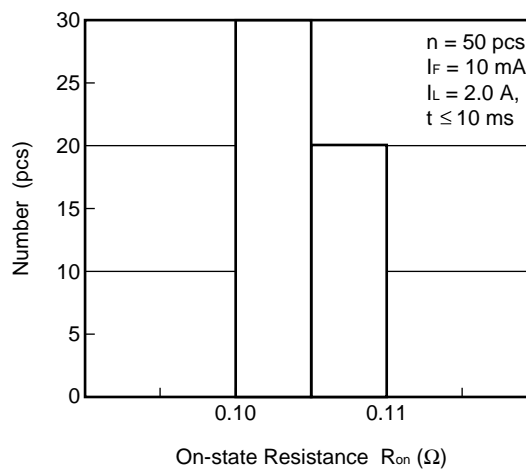
**LOAD CURRENT vs. LOAD VOLTAGE**



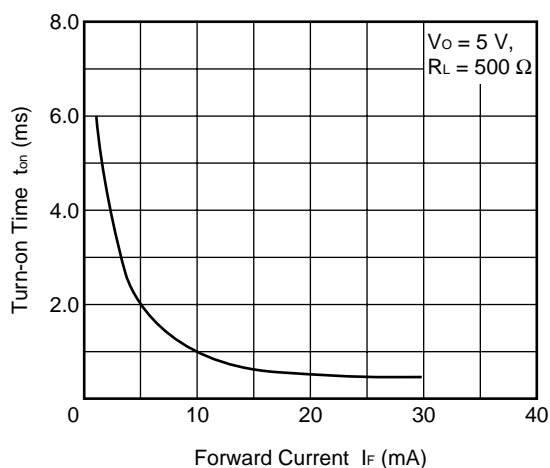
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



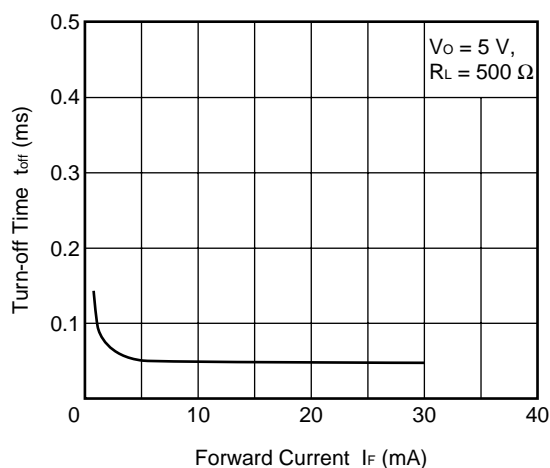
ON-STATE RESISTANCE DISTRIBUTION



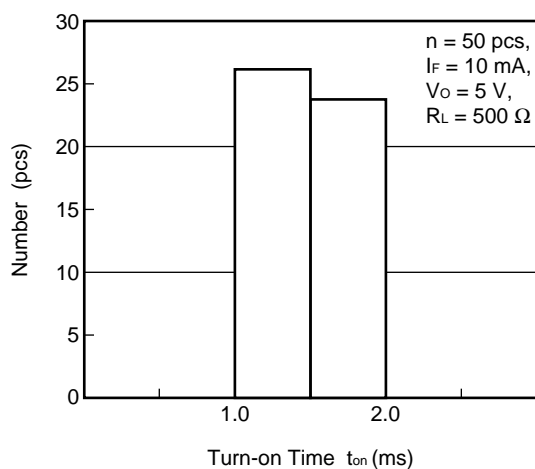
TURN-ON TIME vs. FORWARD CURRENT



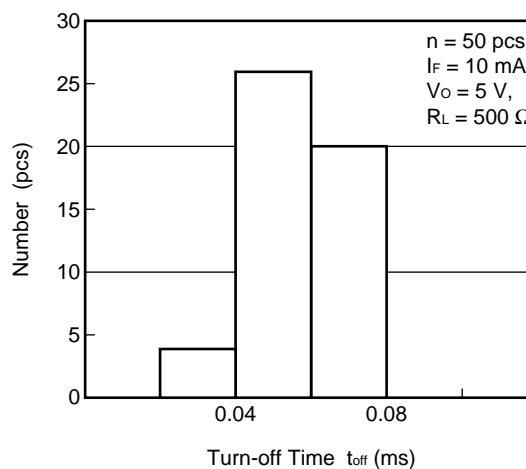
TURN-OFF TIME vs. FORWARD CURRENT



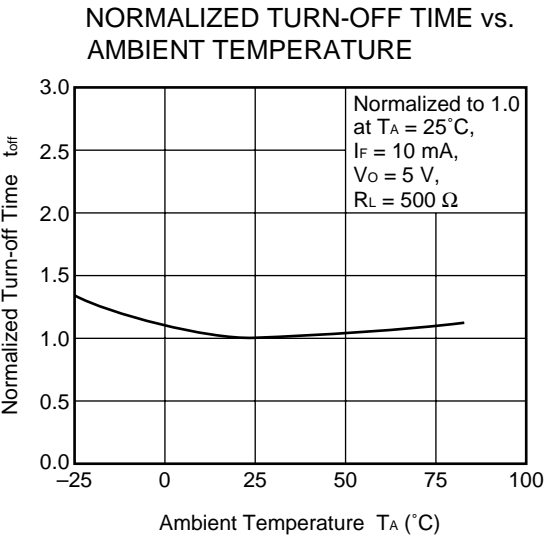
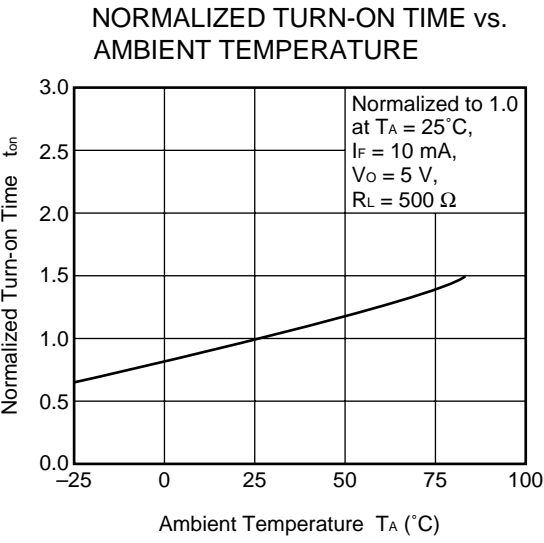
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION



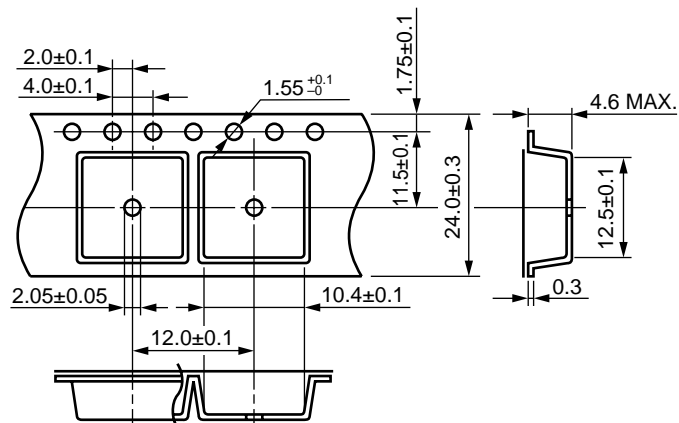




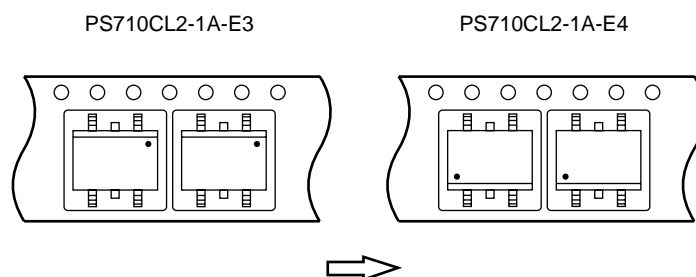
**Remark** The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

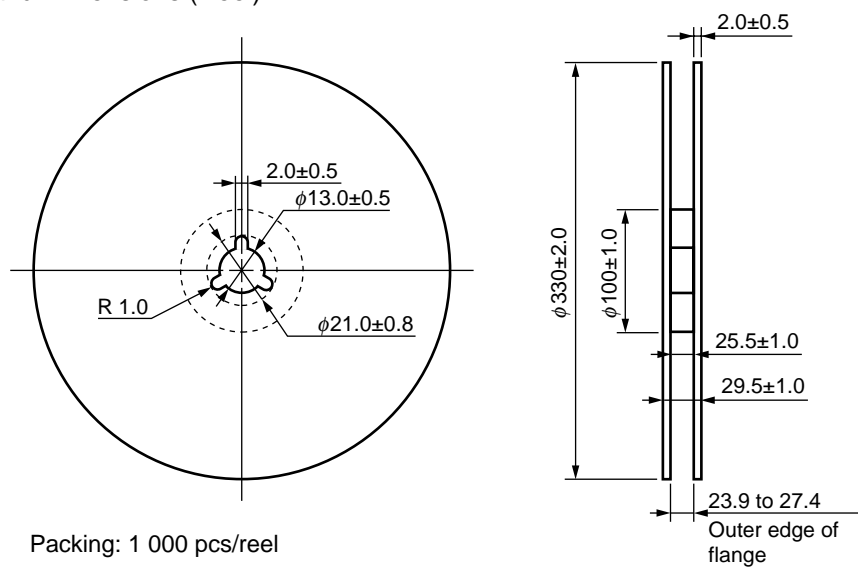
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)

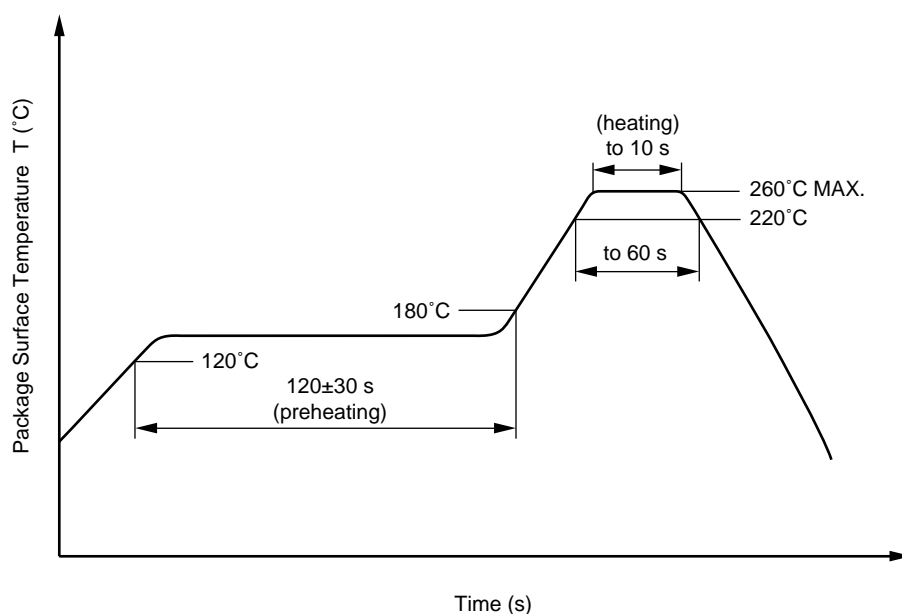


## RECOMMENDED SOLDERING CONDITIONS

### (1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



### (2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

### (3) Cautions

- Fluxes
  - Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

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M8E 00.4-0110

**SAFETY INFORMATION ON THIS PRODUCT**

<b>Caution</b>	GaAs Products	<p>The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested.</p> <ul style="list-style-type: none"> <li>• Do not destroy or burn the product.</li> <li>• Do not cut or cleave off any part of the product.</li> <li>• Do not crush or chemically dissolve the product.</li> <li>• Do not put the product in the mouth.</li> </ul> <p>Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.</p>
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► **Business issue**

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► **Technical issue**

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